## NSN 5961-01-347-8868

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Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-347-8868 **Inclosure Material:** Metal **Overall Length:** Between 0.640 inches and 0.786 inches **Terminal Length:** Between 0.125 inches and 0.180 inches **Overall Height:** 0.200 inches **Overall Width:** Between 0.275 inches and 0.310 inches **End Application:** Tsec/kg-194 **Component Name And Quantity:** 4 transistor **Mounting Method: Terminal Features Provided:** Hermetically sealed case and electrostatic sensitive **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 30.0 drain to source voltage 1st transistor and 30.0 drain to gate voltage 1st transistor **Current Rating Per Characteristic:** 1.00 milliamperes drain current 2nd transistor and 200.00 milliamperes collector current, dc 2nd transistor **Power Rating Per Characteristic:** 2.0 watts total device dissipation all transistor **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Terminal Type And Quantity:** 14 pin **Specification Data:** 98230-0n370557 manufacturers specification control Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: